2SAR542P / 2SAR542D

PNP -5.0A -30V Middle Power Transistor

Datasheet

Collector

Emitter

2SAR542D

(SC-63)

<SOT-428>

CPT3

Base

Parameter	Value
V _{CEO}	-30V
Ι _C	-5.0A

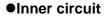
Features

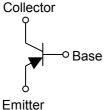
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types : 2SCR542P / 2SCR542D
- 3) Low V_{CE(sat)}

 $V_{CE(sat)}$ = -0.4V Max. (I_C/I_B= -2A/ -100mA)

4) Lead Free/RoHS Compliant.

Packaging specifications





Applications

Outline

Base

Collector

Emitter

2SAR542P

(SC-62)

<SOT-89>

MPT3

Motor driver , LED driver Power supply

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SAR542P	MPT3	4540	T100	180	12	1,000	MQ
2SAR542D	CPT3	6595	TL	330	16	2,500	AR542

●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V _{CBO}	-30	V
Collector-emitter voltage		V _{CEO}	-30	V
Emitter-base voltage		V _{EBO}	-6	V
Collector current	DC	Ι _C	-5.0	Α
	Pulsed	I _{CP} ^{*1}	-10	Α
	2SAR533P		0.5 *2	W
Power dissipation	23AR333F		2.0 ^{*3}	W
rower dissipation	2SAR533D	' D	1.0 ^{*4}	W
	20410000		10 ^{*5}	W
Junction temperature		Tj	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

*1 Pw=10ms, single pulse *2 Each terminal mounted on a reference land

*3 Mounted on a ceramic board (40×40×0.7mm) *4 Mounted on a substrate *5 T_C=25°C

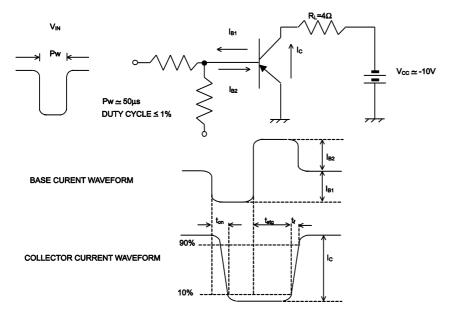
•Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = -100μA	-30	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = -100μA	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -30V	-	-	-1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-1	μA
Collector-emitter saturation voltage	V _{CE(sat)} ^{*1}	$I_{\rm C} = -2A, \ I_{\rm B} = -100 {\rm mA}$	-	-0.20	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -500 \text{mA}$	200	-	500	-
Transition frequency	f _T	V _{CE} = -10V, I _E = 100mA f=100MH _Z	-	240	-	MHz
Output capacitance	C _{ob}	V _{CB} = -10V, I _E = 0A, f = 1MHz	-	40	-	pF
Turn-on time	t _{on} *2	I _C = -2.5A	-	45	-	ns
Storage time	t _{stg} *2	I _{B1} = –250mA I _{B2} =250mA	-	200	-	ns
Fall time	t_{f} *2	V _{CC} ≃ −10V	-	25	-	ns

*1 Pulsed

*2 See switching time test circuit

•Switching time test circuit



•Electrical characteristic curves(Ta = 25°C)

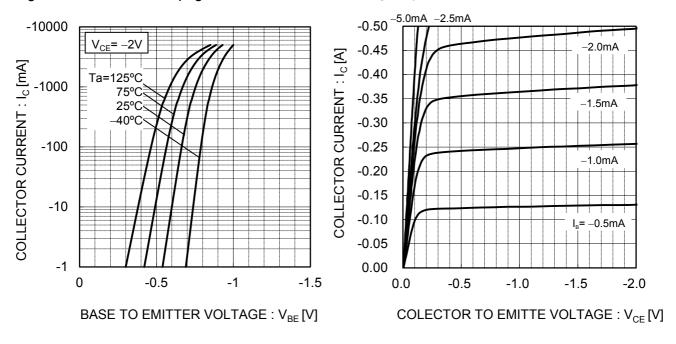
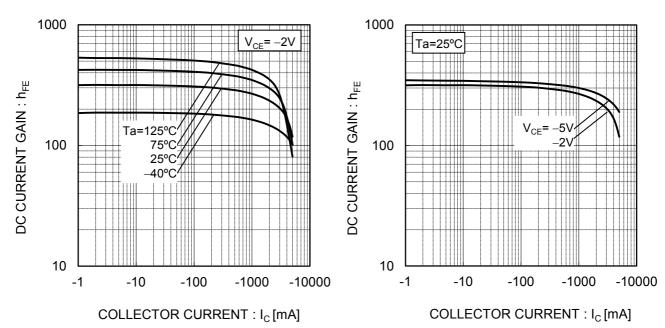


Fig.1 Ground Emitter Propagation Characteristics

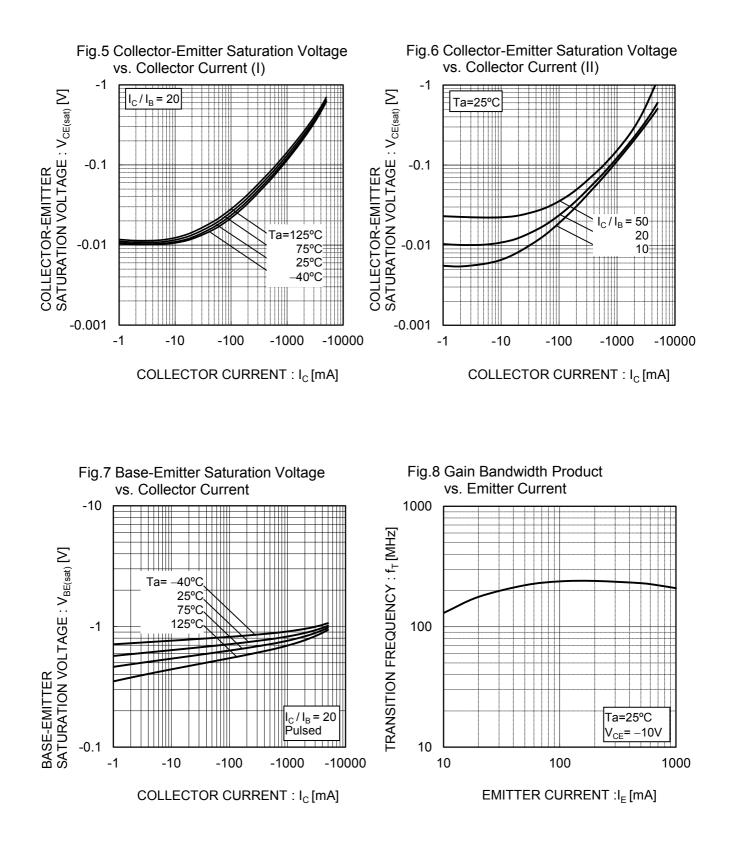
Fig.3 DC Current Gain vs. Collector Current(I)

Fig.4 DC current gain vs. output current (II)

Fig.2 Typical Output Characteristics



•Electrical characteristic curves(Ta = 25°C)



•Electrical characteristic curves(Ta = 25°C)

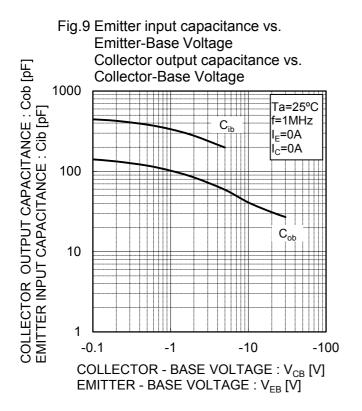
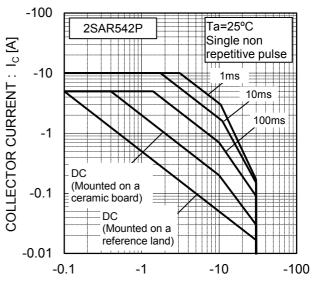
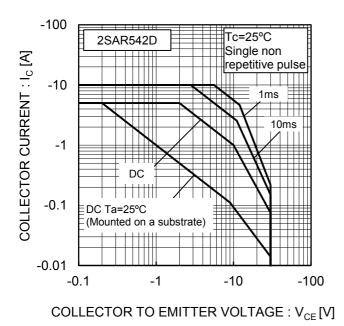


Fig.10 Safe Operating Area

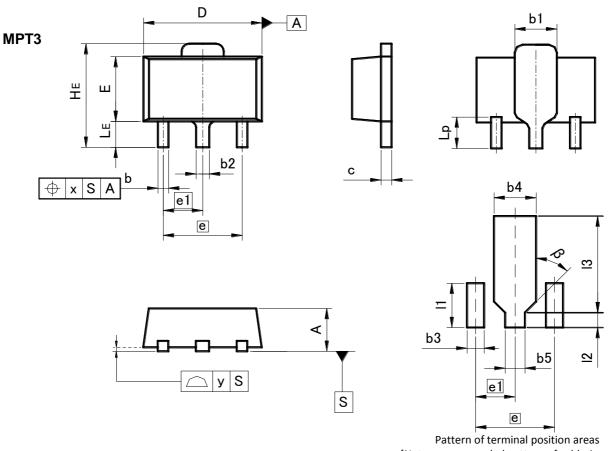


COLLECTOR TO EMITTER VOLTAGE : V_{CE}[V]

Fig.11 Safe Operating Area



•Dimensions (Unit : mm)

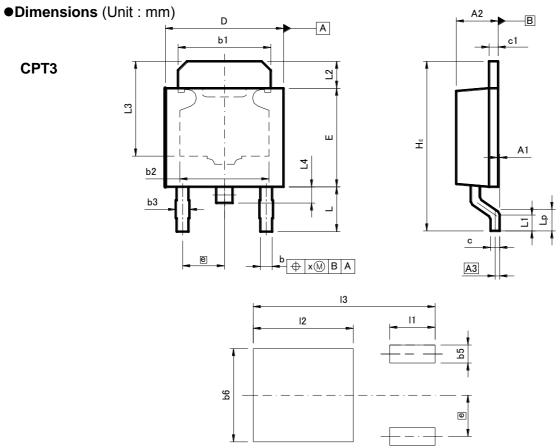


[Not a recommended pattern of soldering pads]

		ETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
A	1.40	1.50	0.055	0.059
b	0.30	0.50	0.012	0.020
b1	1.50	1.70	0.059	0.067
b2	0.40	0.60	0.016	0.024
С	0.35	0.50	0.014	0.020
D	4.40	4.70	0.173	0.185
E	2.40	2.70	0.094	0.106
е	3.0	00	0.1	18
e1	1.	50	0.059	
HE	3.70	4.30	0.146	0.169
LE	0.80	1.20	0.031	0.047
Lp	1.01	1.41	0.040	0.056
х	-	0.15	_	0.006
У	_	0.10	_	0.004

DIM	MILIM	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
b3	-	0.65	-	0.026
b4	-	1.70	-	0.067
b5	-	0.75	-	0.030
1		1.71	-	0.067
12		0.58	-	0.023
13	_	3.72	_	0.146
β	45°		45	0

Dimension in mm / inches



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.15	0.000	0.006
A2	2.20	2.50	0.087	0.098
A3	0.	25	0.0	10
b	0.55	0.75	0.022	0.030
b1	5.00	5.30	0.197	0.209
b2	5.	00	0.1	97
b3	0.	75	0.0	30
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
E	5.40	5.80	0.213	0.228
е	2.	30	0.091	
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.110
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.90		0.0	35
Lp	1.00	1.60	0.039	0.063
х	_	0.25	_	0.010

	MILIM	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
b5	_	1.00	-	0.04
b6	-	5.20	-	0.205
1	-	2.50	-	0.098
12	-	5.50	-	0.217
13	-	10.00	-	0.394

Dimension in mm / inches

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